

1.2-V, 12/10/8-BIT, 200-KSPS/100-KSPS, MICRO-POWER, MINIATURE ANALOG-TO-DIGITAL CONVERTER WITH SERIAL INTERFACE

FEATURES

- Single 1.2-V to 3.6-V Supply Operation
- High Throughput
 - 200/240/280KSPS for 12/10/8-Bit $V_{DD} \geq 1.6$ V
 - 100/120/140KSPS for 12/10/8-Bit $V_{DD} \geq 1.2$ V
- ± 1.5 LSB INL, 12-Bit NMC (ADS7866)
- 71 dB SNR, -83 dB THD at $f_{IN} = 30$ kHz (ADS7866)
- Synchronized Conversion with SCLK
- SPI Compatible Serial Interface
- No Pipeline Delays
- Low Power
 - 1.39 mW Typ at 200 KSPS, $V_{DD} = 3.6$ V
 - 0.39 mW Typ at 200 KSPS, $V_{DD} = 1.6$ V
 - 0.22 mW Typ at 100 KSPS, $V_{DD} = 1.2$ V
- Auto Power-Down: 8 nA Typ, 300 nA Max
- 0 V to V_{DD} Unipolar Input Range
- 6-Pin SOT-23 Package

APPLICATIONS

- Battery Powered Systems
- Isolated Data Acquisition
- Medical Instruments
- Portable Communication
- Portable Data Acquisition Systems
- Automatic Test Equipment

DESCRIPTION

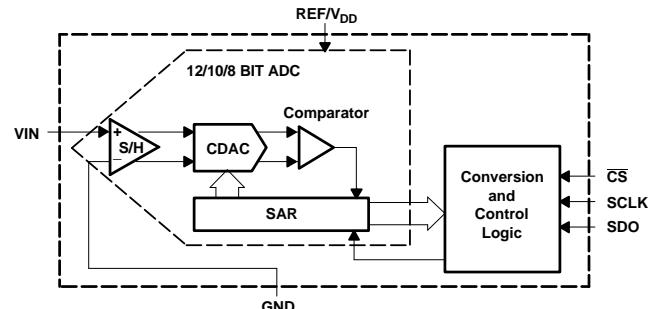
The ADS7866/67/68 are low power, miniature, 12/10/8-bit A/D converters each with a unipolar, single-ended input. These devices can operate from a single 1.6 V to 3.6 V supply with a 200-KSPS throughput for ADS7866. In addition, these devices can maintain at least a 100-KSPS throughput with a supply as low as 1.2 V.

The sampling, conversion, and activation of digital output SDO are initiated on the falling edge of CS. The serial clock SCLK is used for controlling the conversion rate and shifting data out of the converter. Furthermore, SCLK provides a mechanism to allow digital host processors to synchronize with the converter. These converters interface with micro-processors or DSPs through a high-speed SPI compatible serial interface. There are no pipeline delays associated with the device.

The minimum conversion time is determined by the frequency of the serial clock input, SCLK, while the maximum frequency of SCLK is determined by the minimum sampling time required to charge the input capacitance to 12/10/8-bit accuracy for the ADS7866/67/68, respectively. The maximum throughput is determined by how often a conversion is initiated when the minimum sampling time is met and the maximum SCLK frequency is used. Each device automatically powers down after each conversion, which allows each device to save power when the throughput is reduced while using the maximum SCLK frequency.

The converter reference is taken internally from the supply. Hence, the analog input range for these devices is 0 V to V_{DD} .

These devices are available in a 6-pin SOT-23 package and are characterized over the industrial -40°C to 85°C temperature range.



Micro-Power Miniature SAR Converter Family

RESOLUTION/SPEED	< 200 KSPS	1 MSPS – 1.25 MSPS
12-Bit	ADS7866 (1.2 V_{DD} to 3.6 V_{DD})	ADS7886 (2.35 V_{DD} to 5.25 V_{DD})
10-Bit	ADS7867 (1.2 V_{DD} to 3.6 V_{DD})	ADS7887 (2.35 V_{DD} to 5.25 V_{DD})
8-Bit	ADS7868 (1.2 V_{DD} to 3.6 V_{DD})	ADS7888 (2.35 V_{DD} to 5.25 V_{DD})



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ORDERING INFORMATION⁽¹⁾

MODEL	MAXIMUM INTEGRAL LINEARITY (LSB)	MAXIMUM DIFFERENTIAL LINEARITY (LSB)	NO MISSING CODES RESOLUTION (BIT)	PACKAGE TYPE	PACKAGE MARKING (SYMBOL)	PACKAGE DESIGNATOR	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	TRANSPORT MEDIA, QUANTITY
ADS7866I	± 1.5	$-1/+1.5$	12	SOT23-6	A66Y	DBV	-40°C to 85°C	ADS7866IDBVT	Small tape and reel, 250
ADS7866I	± 1.5	$-1/+1.5$	12	SOT23-6	A66Y	DBV	-40°C to 85°C	ADS7866IDBVR	Tape and reel, 3000
ADS7867I	± 0.5	± 0.5	10	SOT23-6	A67Y	DBV	-40°C to 85°C	ADS7867IDBVT	Small tape and reel, 250
ADS7867I	± 0.5	± 0.5	10	SOT23-6	A67Y	DBV	-40°C to 85°C	ADS7867IDBVR	Tape and reel, 3000
ADS7868I	± 0.5	± 0.5	8	SOT23-6	A68Y	DBV	-40°C to 85°C	ADS7868IDBVT	Small tape and reel, 250
ADS7868I	± 0.5	± 0.5	8	SOT23-6	A68Y	DBV	-40°C to 85°C	ADS7868IDBVR	Tape and reel, 3000

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)

		RATING
V_{DD} to GND		-0.3 V to 4.0 V
Analog input voltage to GND		-0.3 V to $V_{DD} + 0.3$ V
Digital input voltage to GND		-0.3 V to 4.0 V
Digital output voltage to GND		-0.3 V to $V_{DD} + 0.3$ V
T_A	Operating free-air temperature range	-40°C to 85°C
$T_{STORAGE}$	Storage temperature range	-65°C to 150°C
T_J	Junction temperature	150°C
SOT-23 Package	θ_{JA} Thermal impedance	$110.9^{\circ}\text{C}/\text{W}$
	θ_{JC} Thermal impedance	$22.31^{\circ}\text{C}/\text{W}$
Lead temperature, soldering	Vapor phase (10–40 sec)	250°C
	Infrared (10–30 sec)	260°C
ESD		3 kV

SPECIFICATIONS, ADS7866

At -40°C to 85°C , $f_{\text{SAMPLE}} = 200$ KSPS and $f_{\text{SCLK}} = 3.4$ MHz if $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6 \text{ V}$; $f_{\text{SAMPLE}} = 100$ KSPS and $f_{\text{SCLK}} = 1.7$ MHz if $1.2 \text{ V} \leq V_{\text{DD}} < 1.6 \text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SYSTEM PERFORMANCE					
Resolution		12			Bits
No missing codes		12			Bits
Integral linearity		-1.5	1.5		LSB ⁽¹⁾
Differential linearity		-1	1.5		LSB
Offset error ⁽²⁾	1.2 V $\leq V_{\text{DD}} < 1.6$ V	-2	2		LSB
	1.6 V $\leq V_{\text{DD}} \leq 3.6$ V	-3	3		
Gain error ⁽³⁾	1.2 V $\leq V_{\text{DD}} < 1.6$ V	-2	2		LSB
	1.6 V $\leq V_{\text{DD}} \leq 3.6$ V	-2	2		
Total unadjusted error ⁽⁴⁾	1.2 V $\leq V_{\text{DD}} < 1.6$ V	-2.5	2.5		LSB
	1.6 V $\leq V_{\text{DD}} \leq 3.6$ V	-3.5	3.5		
SAMPLING DYNAMICS (See Timing Characteristics Section)					
t_{CONVERT}	Conversion time $f_{\text{SCLK}} = 3.4$ MHz, 13 SCLK cycles	3.82			μs
t_{SAMPLE}	Acquisition time $f_{\text{SCLK}} = 3.4$ MHz, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	0.64			μs
f_{SAMPLE}	Throughput rate $f_{\text{SCLK}} = 3.4$ MHz, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V		200		KSPS
Aperture delay		10			ns
Aperture jitter		40			ps
DYNAMIC CHARACTERISTICS					
SINAD	$f_{\text{IN}} = 30$ kHz, $1.2 \text{ V} \leq V_{\text{DD}} < 1.6$ V	68			dB
	$f_{\text{IN}} = 30$ kHz, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	69	70		
SNR	$f_{\text{IN}} = 30$ kHz, $1.2 \text{ V} \leq V_{\text{DD}} < 1.6$ V	70			dB
	$f_{\text{IN}} = 30$ kHz, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	70	71		
THD	$f_{\text{IN}} = 30$ kHz, $1.2 \text{ V} \leq V_{\text{DD}} < 1.6$ V	-70			dB
	$f_{\text{IN}} = 30$ kHz, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	-83			
SFDR	$f_{\text{IN}} = 30$ kHz, $1.2 \text{ V} \leq V_{\text{DD}} < 1.6$ V	75			dB
	$f_{\text{IN}} = 30$ kHz, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	85			
Full-power bandwidth ⁽⁶⁾	At 0.1 dB, $1.2 \text{ V} \leq V_{\text{DD}} < 1.6$ V	2			MHz
	At 0.1 dB, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	4			
	At 3 dB, $1.2 \text{ V} \leq V_{\text{DD}} < 1.6$ V	3			
	At 3 dB, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	8			
ANALOG INPUT					
Full-scale input span ⁽⁷⁾	VIN – GND	0	V_{DD}		V
C_s	Input capacitance		12		pF
	Input leakage current	-1	1		μA
DIGITAL INPUT					
Logic family , CMOS					
V_{IH}	$1.2 \text{ V} \leq V_{\text{DD}} < 1.6$ V	$0.7 \times V_{\text{DD}}$	3.6		V
	$1.6 \text{ V} \leq V_{\text{DD}} < 1.8$ V	$0.7 \times V_{\text{DD}}$	3.6		
	$1.8 \text{ V} \leq V_{\text{DD}} < 2.5$ V	$0.7 \times V_{\text{DD}}$	3.6		
	$2.5 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	2	3.6		

(1) LSB = Least Significant Bit

(2) The difference in the first code transition 000...000 to 000...001 from the ideal value of GND + 1 LSB.

(3) The difference in the last code transition 011...111 to 111...111 from the ideal value of $V_{\text{DD}} - 1$ LSB with the offset error removed.

(4) The absolute difference from the ideal transfer function of the converter. This specification is similar to INL error except the effects of offset error and gain error are included.

(5) The 2nd through 10th harmonics are used to determine THD.

(6) Input frequency where the amplitude of the digitized signal has decreased by 0.1 dB or 3 dB.

(7) Ideal input span which does not include gain or offset errors.

SPECIFICATIONS, ADS7866 (continued)

At -40°C to 85°C , $f_{\text{SAMPLE}} = 200 \text{ KSPS}$ and $f_{\text{SCLK}} = 3.4 \text{ MHz}$ if $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6 \text{ V}$; $f_{\text{SAMPLE}} = 100 \text{ KSPS}$ and $f_{\text{SCLK}} = 1.7 \text{ MHz}$ if $1.2 \text{ V} \leq V_{\text{DD}} < 1.6 \text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IL} Input logic low level	$1.2 \text{ V} \leq V_{\text{DD}} < 1.6 \text{ V}$	-0.2	$0.2 \times V_{\text{DD}}$		V
	$1.6 \text{ V} \leq V_{\text{DD}} < 1.8 \text{ V}$	-0.2	$0.2 \times V_{\text{DD}}$		
	$1.8 \text{ V} \leq V_{\text{DD}} < 2.5 \text{ V}$	-0.2	$0.3 \times V_{\text{DD}}$		
	$2.5 \text{ V} \leq V_{\text{DD}} \leq 3.6 \text{ V}$	-0.2	0.8		
I_{SCLK}	SCLK pin leakage current	-1	0.02	1	μA
I_{CS}	CS pin leakage current		± 1		μA
C_{IN}	Digital input pin capacitance		10		pF
DIGITAL OUTPUT					
V_{OH}	Output logic high level	$I_{\text{SOURCE}} = 200 \mu\text{A}$	$V_{\text{DD}} - 0.2$	V_{DD}	V
V_{OL}	Output logic low level	$I_{\text{SINK}} = 200 \mu\text{A}$	0	0.2	V
I_{SDO}	SDO pin leakage current	Floating output	-1	1	μA
C_{OUT}	Digital output pin capacitance	Floating output		10	pF
	Data format, straight binary				
POWER SUPPLY REQUIREMENTS					
V_{DD}	Supply voltage		1.2	3.6	V
I_{DD} Supply current, normal operation	Digital inputs = 0 V or V_{DD}	$f_{\text{SAMPLE}} = 200 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 3.6 \text{ V}$	385	500	μA
		$f_{\text{SAMPLE}} = 100 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 3.6 \text{ V}$	193		
		$f_{\text{SAMPLE}} = 50 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 3.6 \text{ V}$	97		
		$f_{\text{SAMPLE}} = 20 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 3.6 \text{ V}$	39		
		$f_{\text{SAMPLE}} = 200 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 3 \text{ V}$	340		μA
		$f_{\text{SAMPLE}} = 100 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 3 \text{ V}$	170		
		$f_{\text{SAMPLE}} = 50 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 3 \text{ V}$	85		
		$f_{\text{SAMPLE}} = 20 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 3 \text{ V}$	35		
		$f_{\text{SAMPLE}} = 200 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 2.5 \text{ V}$	305		μA
		$f_{\text{SAMPLE}} = 100 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 2.5 \text{ V}$	153		
		$f_{\text{SAMPLE}} = 50 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 2.5 \text{ V}$	77		
		$f_{\text{SAMPLE}} = 20 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 2.5 \text{ V}$	31		
		$f_{\text{SAMPLE}} = 200 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 1.8 \text{ V}$	256		μA
		$f_{\text{SAMPLE}} = 100 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 1.8 \text{ V}$	128		
		$f_{\text{SAMPLE}} = 50 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 1.8 \text{ V}$	65		
		$f_{\text{SAMPLE}} = 20 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 1.8 \text{ V}$	26		
		$f_{\text{SAMPLE}} = 200 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 1.6 \text{ V}$	241	330	μA
		$f_{\text{SAMPLE}} = 100 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 1.6 \text{ V}$	121		
		$f_{\text{SAMPLE}} = 50 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 1.6 \text{ V}$	61		
		$f_{\text{SAMPLE}} = 20 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 1.6 \text{ V}$	25		
		$f_{\text{SAMPLE}} = 100 \text{ KSPS}, f_{\text{SCLK}} = 1.7 \text{ MHz}, V_{\text{DD}} = 1.2 \text{ V}$	186	250	μA
		$f_{\text{SAMPLE}} = 50 \text{ KSPS}, f_{\text{SCLK}} = 1.7 \text{ MHz}, V_{\text{DD}} = 1.2 \text{ V}$	93		
		$f_{\text{SAMPLE}} = 20 \text{ KSPS}, f_{\text{SCLK}} = 1.7 \text{ MHz}, V_{\text{DD}} = 1.2 \text{ V}$	37		
I_{DD}	Power-down mode	SCLK on or off	0.008	0.3	μA
POWER DISSIPATION					
Normal operation		$f_{\text{SAMPLE}} = 200 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 3.6 \text{ V}$	1.39	1.80	mW
		$f_{\text{SAMPLE}} = 200 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 1.6 \text{ V}$	0.39	0.53	
		$f_{\text{SAMPLE}} = 100 \text{ KSPS}, f_{\text{SCLK}} = 1.7 \text{ MHz}, V_{\text{DD}} = 1.2 \text{ V}$	0.22	0.3	
Power-down mode		SCLK on or off, $V_{\text{DD}} = 3.6 \text{ V}$	1.08		μW
TEMPERATURE RANGE					
Specified performance			-40	85	$^{\circ}\text{C}$

SPECIFICATIONS, ADS7867

At -40°C to 85°C , $f_{\text{SAMPLE}} = 240$ KSPS and $f_{\text{SCLK}} = 3.4$ MHz if $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6 \text{ V}$; $f_{\text{SAMPLE}} = 120$ KSPS and $f_{\text{SCLK}} = 1.7$ MHz if $1.2 \text{ V} \leq V_{\text{DD}} < 1.6 \text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SYSTEM PERFORMANCE					
Resolution		10			Bits
No missing codes		10			Bits
Integral linearity		-0.5	0.5		LSB ⁽¹⁾
Differential linearity		-0.5	0.5		LSB
Offset error ⁽²⁾	1.2 V $\leq V_{\text{DD}} < 1.6$ V	-0.75	0.75		LSB
	1.6 V $\leq V_{\text{DD}} \leq 3.6$ V	-1	1		
Gain error ⁽³⁾	1.2 V $\leq V_{\text{DD}} < 1.6$ V	-0.5	0.5		LSB
	1.6 V $\leq V_{\text{DD}} \leq 3.6$ V	-0.5	0.5		
Total unadjusted error ⁽⁴⁾	1.2 V $\leq V_{\text{DD}} < 1.6$ V	-2	2		LSB
	1.6 V $\leq V_{\text{DD}} \leq 3.6$ V	-2	2		
SAMPLING DYNAMICS (See Timing Characteristics Section)					
t_{CONVERT}	Conversion time	$f_{\text{SCLK}} = 3.4$ MHz, 11 SCLK cycles	3.235		μs
t_{SAMPLE}	Acquisition time	$f_{\text{SCLK}} = 3.4$ MHz, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	0.64		μs
f_{SAMPLE}	Throughput rate	$f_{\text{SCLK}} = 3.4$ MHz, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V		240	KSPS
	Aperture delay		10		ns
	Aperture jitter		40		ps
DYNAMIC CHARACTERISTICS					
SINAD	Signal-to-noise and distortion	$f_{\text{SAMPLE}} = 100$ KSPS, $f_{\text{IN}} = 30$ kHz, $1.2 \text{ V} \leq V_{\text{DD}} < 1.6$ V	61		dB
		$f_{\text{SAMPLE}} = 200$ KSPS, $f_{\text{IN}} = 30$ kHz, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	61	61.7	
SNR	Signal-to-noise ratio	$f_{\text{SAMPLE}} = 100$ KSPS, $f_{\text{IN}} = 30$ kHz, $1.2 \text{ V} \leq V_{\text{DD}} < 1.6$ V	61.5		dB
		$f_{\text{SAMPLE}} = 200$ KSPS, $f_{\text{IN}} = 30$ kHz, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	61.8		
THD	Total harmonic distortion ⁽⁵⁾	$f_{\text{SAMPLE}} = 100$ KSPS, $f_{\text{IN}} = 30$ kHz, $1.2 \text{ V} \leq V_{\text{DD}} < 1.6$ V	-68		dB
		$f_{\text{SAMPLE}} = 200$ KSPS, $f_{\text{IN}} = 30$ kHz, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	-78	-72	
SFDR	Spurious free dynamic range	$f_{\text{SAMPLE}} = 100$ KSPS, $f_{\text{IN}} = 30$ kHz, $1.2 \text{ V} \leq V_{\text{DD}} < 1.6$ V	73		dB
		$f_{\text{SAMPLE}} = 200$ KSPS, $f_{\text{IN}} = 30$ kHz, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	74	80	
Full-power bandwidth ⁽⁶⁾		At 0.1 dB, $1.2 \text{ V} \leq V_{\text{DD}} < 1.6$ V	2		MHz
		At 0.1 dB, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	4		
		At 3 dB, $1.2 \text{ V} \leq V_{\text{DD}} < 1.6$ V	3		
		At 3 dB, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	8		
ANALOG INPUT					
Full-scale input span ⁽⁷⁾	VIN – GND	0	V_{DD}		V
C_s	Input capacitance		12		pF
	Input leakage current	-1	1		μA
DIGITAL INPUT					
Logic family, CMOS					
V_{IH}	Input logic high level	1.2 V $\leq V_{\text{DD}} < 1.6$ V	$0.7 \times V_{\text{DD}}$	3.6	V
		1.6 V $\leq V_{\text{DD}} < 1.8$ V	$0.7 \times V_{\text{DD}}$	3.6	
		1.8 V $\leq V_{\text{DD}} < 2.5$ V	$0.7 \times V_{\text{DD}}$	3.6	
		2.5 V $\leq V_{\text{DD}} \leq 3.6$ V	2	3.6	

(1) LSB = Least Significant Bit

(2) The difference in the first code transition 000...000 to 000...001 from the ideal value of GND + 1 LSB.

(3) The difference in the last code transition 011...111 to 111...111 from the ideal value of $V_{\text{DD}} - 1$ LSB with the offset error removed.

(4) The absolute difference from the ideal transfer function of the converter. This specification is similar to INL error except the effects of offset error and gain error are included.

(5) The 2nd through 10th harmonics are used to determine THD.

(6) Input frequency where the amplitude of the digitized signal has decreased by 0.1 dB or 3 dB.

(7) Ideal input span which does not include gain or offset errors.

SPECIFICATIONS, ADS7867 (continued)

At -40°C to 85°C , $f_{\text{SAMPLE}} = 240$ KSPS and $f_{\text{SCLK}} = 3.4$ MHz if $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6 \text{ V}$; $f_{\text{SAMPLE}} = 120$ KSPS and $f_{\text{SCLK}} = 1.7$ MHz if $1.2 \text{ V} \leq V_{\text{DD}} < 1.6 \text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IL} Input logic low level	$1.2 \text{ V} \leq V_{\text{DD}} < 1.6 \text{ V}$	-0.2	$0.2 \times V_{\text{DD}}$		V
	$1.6 \text{ V} \leq V_{\text{DD}} < 1.8 \text{ V}$	-0.2	$0.2 \times V_{\text{DD}}$		
	$1.8 \text{ V} \leq V_{\text{DD}} < 2.5 \text{ V}$	-0.2	$0.3 \times V_{\text{DD}}$		
	$2.5 \text{ V} \leq V_{\text{DD}} \leq 3.6 \text{ V}$	-0.2	0.8		
I_{SCLK}	SCLK pin leakage current Digital input = 0 V or V_{DD}	-1	0.02	1	μA
I_{CS}	$\overline{\text{CS}}$ pin leakage current		± 1		μA
C_{IN}	Digital input pin capacitance			10	pF
DIGITAL OUTPUT					
V_{OH}	Output logic high level $I_{\text{SOURCE}} = 200 \mu\text{A}$	$V_{\text{DD}} - 0.2$	V_{DD}	V	
V_{OL}	Output logic low level $I_{\text{SINK}} = 200 \mu\text{A}$	0	0.2	V	
I_{SDO}	SDO pin leakage current Floating output	-1	1	μA	
C_{OUT}	Digital output pin capacitance Floating output			10	pF
	Data format, straight binary				
POWER SUPPLY REQUIREMENTS					
V_{DD}	Supply voltage		1.2	3.6	V
I_{DD} Supply current, normal operation	Digital Inputs = 0 V or V_{DD}	$f_{\text{SAMPLE}} = 240$ KSPS, $f_{\text{SCLK}} = 3.4$ MHz, $V_{\text{DD}} = 3.6$ V	420	500	μA
		$f_{\text{SAMPLE}} = 100$ KSPS, $f_{\text{SCLK}} = 3.4$ MHz, $V_{\text{DD}} = 3.6$ V	172		
		$f_{\text{SAMPLE}} = 240$ KSPS, $f_{\text{SCLK}} = 3.4$ MHz, $V_{\text{DD}} = 1.6$ V	261	330	μA
		$f_{\text{SAMPLE}} = 100$ KSPS, $f_{\text{SCLK}} = 3.4$ MHz, $V_{\text{DD}} = 1.6$ V	107		
		$f_{\text{SAMPLE}} = 120$ KSPS, $f_{\text{SCLK}} = 1.7$ MHz, $V_{\text{DD}} = 1.2$ V	202	250	μA
		$f_{\text{SAMPLE}} = 50$ KSPS, $f_{\text{SCLK}} = 1.7$ MHz, $V_{\text{DD}} = 1.2$ V	83		
I_{DD}	Power-down mode SCLK on or off		0.008	0.3	μA
POWER DISSIPATION					
Normal operation		$f_{\text{SAMPLE}} = 240$ KSPS, $f_{\text{SCLK}} = 3.4$ MHz, $V_{\text{DD}} = 3.6$ V	1.51	1.80	mW
		$f_{\text{SAMPLE}} = 240$ KSPS, $f_{\text{SCLK}} = 3.4$ MHz, $V_{\text{DD}} = 1.6$ V	0.42	0.53	
		$f_{\text{SAMPLE}} = 120$ KSPS, $f_{\text{SCLK}} = 1.7$ MHz, $V_{\text{DD}} = 1.2$ V	0.24	0.30	
Power-down mode	SCLK on or off, $V_{\text{DD}} = 3.6$ V			1.08	μW
TEMPERATURE RANGE					
Specified performance		-40	85	$^{\circ}\text{C}$	

SPECIFICATIONS, ADS7868

At -40°C to 85°C , $f_{\text{SAMPLE}} = 280$ KSPS and $f_{\text{SCLK}} = 3.4$ MHz if $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6 \text{ V}$; $f_{\text{SAMPLE}} = 140$ KSPS and $f_{\text{SCLK}} = 1.7$ MHz if $1.2 \text{ V} \leq V_{\text{DD}} < 1.6 \text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SYSTEM PERFORMANCE					
Resolution		8			Bits
No missing codes		8			Bits
Integral linearity		-0.5	0.5		LSB ⁽¹⁾
Differential linearity		-0.5	0.5		LSB
Offset error ⁽²⁾	1.2 V $\leq V_{\text{DD}} < 1.6$ V	-0.5	0.5		LSB
	1.6 V $\leq V_{\text{DD}} \leq 3.6$ V	-0.5	0.5		
Gain error ⁽³⁾	1.2 V $\leq V_{\text{DD}} < 1.6$ V	-0.5	0.5		LSB
	1.6 V $\leq V_{\text{DD}} \leq 3.6$ V	-0.5	0.5		
Total unadjusted error ⁽⁴⁾	1.2 V $\leq V_{\text{DD}} < 1.6$ V	-1	1		LSB
	1.6 V $\leq V_{\text{DD}} \leq 3.6$ V	-1	1		
SAMPLING DYNAMICS (See Timing Characteristics Section)					
t_{CONVERT}	Conversion time $f_{\text{SCLK}} = 3.4$ MHz, 9 SCLK cycles	2.647			μs
t_{SAMPLE}	Acquisition time $f_{\text{SCLK}} = 3.4$ MHz, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	0.64			μs
f_{SAMPLE}	Throughput rate $f_{\text{SCLK}} = 3.4$ MHz, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V		280		KSPS
	Aperture delay		10		ns
	Aperture jitter		40		ps
DYNAMIC CHARACTERISTICS					
SINAD	Signal-to-noise and distortion $f_{\text{SAMPLE}} = 100$ KSPS, $f_{\text{IN}} = 30$ kHz, $1.2 \text{ V} \leq V_{\text{DD}} < 1.6$ V	49			dB
	$f_{\text{SAMPLE}} = 200$ KSPS, $f_{\text{IN}} = 30$ kHz, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	49	49.4		
SNR	Signal-to-noise ratio $f_{\text{SAMPLE}} = 100$ KSPS, $f_{\text{IN}} = 30$ kHz, $1.2 \text{ V} \leq V_{\text{DD}} < 1.6$ V	49.4			dB
	$f_{\text{SAMPLE}} = 200$ KSPS, $f_{\text{IN}} = 30$ kHz, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	49.8			
THD	Total harmonic distortion ⁽⁵⁾ $f_{\text{SAMPLE}} = 100$ KSPS, $f_{\text{IN}} = 30$ kHz, $1.2 \text{ V} \leq V_{\text{DD}} < 1.6$ V	-65			dB
	$f_{\text{SAMPLE}} = 200$ KSPS, $f_{\text{IN}} = 30$ kHz, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	-72	-66		
SFDR	Spurious free dynamic range $f_{\text{SAMPLE}} = 100$ KSPS, $f_{\text{IN}} = 30$ kHz, $1.2 \text{ V} \leq V_{\text{DD}} < 1.6$ V	67			dB
	$f_{\text{SAMPLE}} = 200$ KSPS, $f_{\text{IN}} = 30$ kHz, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	66	67		
Full-power bandwidth ⁽⁶⁾	At 0.1 dB, $1.2 \text{ V} \leq V_{\text{DD}} < 1.6$ V	2			MHz
	At 0.1 dB, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	4			
	At 3 dB, $1.2 \text{ V} \leq V_{\text{DD}} < 1.6$ V	3			
	At 3 dB, $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6$ V	8			
ANALOG INPUT					
Full-scale input span ⁽⁷⁾	$V_{\text{IN}} - \text{GND}$	0	V_{DD}		V
C_{S}	Input capacitance		12		pF
	Input leakage current	-1	1		μA
DIGITAL INPUT					
Logic family, CMOS					
V_{IH}	Input logic high level 1.2 V $\leq V_{\text{DD}} < 1.6$ V	$0.7 \times V_{\text{DD}}$	3.6		V
	1.6 V $\leq V_{\text{DD}} < 1.8$ V	$0.7 \times V_{\text{DD}}$	3.6		
	1.8 V $\leq V_{\text{DD}} < 2.5$ V	$0.7 \times V_{\text{DD}}$	3.6		
	2.5 V $\leq V_{\text{DD}} \leq 3.6$ V	2	3.6		

(1) LSB = Least Significant Bit

(2) The difference in the first code transition 000...000 to 000...001 from the ideal value of GND + 1 LSB.

(3) The difference in the last code transition 011...111 to 111...111 from the ideal value of $V_{\text{DD}} - 1$ LSB with the offset error removed.

(4) The absolute difference from the ideal transfer function of the converter. This specification is similar to INL error except the effects of offset error and gain error are included.

(5) The 2nd through 10th harmonics are used to determine THD.

(6) Input frequency where the amplitude of the digitized signal has decreased by 0.1 dB or 3 dB.

(7) Ideal input span which does not include gain or offset errors.

SPECIFICATIONS, ADS7868 (continued)

At -40°C to 85°C , $f_{\text{SAMPLE}} = 280 \text{ KSPS}$ and $f_{\text{SCLK}} = 3.4 \text{ MHz}$ if $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6 \text{ V}$; $f_{\text{SAMPLE}} = 140 \text{ KSPS}$ and $f_{\text{SCLK}} = 1.7 \text{ MHz}$ if $1.2 \text{ V} \leq V_{\text{DD}} < 1.6 \text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{IL} Input logic low level	1.2 V $\leq V_{\text{DD}} < 1.6 \text{ V}$		-0.2	0.2 $\times V_{\text{DD}}$		V
	1.6 V $\leq V_{\text{DD}} < 1.8 \text{ V}$		-0.2	0.2 $\times V_{\text{DD}}$		
	1.8 V $\leq V_{\text{DD}} < 2.5 \text{ V}$		-0.2	0.3 $\times V_{\text{DD}}$		
	2.5 V $\leq V_{\text{DD}} \leq 3.6 \text{ V}$		-0.2	0.8		
I_{SCLK} SCLK pin leakage current	Digital input = 0 V or V_{DD}		-1	0.02	1	μA
I_{CS} $\overline{\text{CS}}$ pin leakage current				± 1		μA
C_{IN} Digital input pin capacitance					10	pF
DIGITAL OUTPUT						
V_{OH} Output logic high level	$I_{\text{SOURCE}} = 200 \mu\text{A}$		$V_{\text{DD}} - 0.2$	V_{DD}		V
V_{OL} Output logic low level	$I_{\text{SINK}} = 200 \mu\text{A}$		0	0.2		V
I_{SDO} SDO pin leakage current	Floating output		-1	1		μA
C_{OUT} Digital output pin capacitance	Floating output				10	pF
Data format, straight binary						
POWER SUPPLY REQUIREMENTS						
V_{DD} Supply voltage			1.2	3.6		V
I_{DD} Supply current, normal operation	Digital Inputs = 0 V or V_{DD}	$f_{\text{SAMPLE}} = 280 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 3.6 \text{ V}$	439	500		μA
		$f_{\text{SAMPLE}} = 100 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 3.6 \text{ V}$	154			
		$f_{\text{SAMPLE}} = 280 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 1.6 \text{ V}$	264	330		
		$f_{\text{SAMPLE}} = 100 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 1.6 \text{ V}$	93			
		$f_{\text{SAMPLE}} = 140 \text{ KSPS}, f_{\text{SCLK}} = 1.7 \text{ MHz}, V_{\text{DD}} = 1.2 \text{ V}$	201	250		
		$f_{\text{SAMPLE}} = 50 \text{ KSPS}, f_{\text{SCLK}} = 1.7 \text{ MHz}, V_{\text{DD}} = 1.2 \text{ V}$	70			
I_{DD} Power-down mode	SCLK on or off		0.008	0.3		μA
POWER DISSIPATION						
Normal operation		$f_{\text{SAMPLE}} = 280 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 3.6 \text{ V}$	1.58	1.8		mW
		$f_{\text{SAMPLE}} = 280 \text{ KSPS}, f_{\text{SCLK}} = 3.4 \text{ MHz}, V_{\text{DD}} = 1.6 \text{ V}$	0.42	0.53		
		$f_{\text{SAMPLE}} = 140 \text{ KSPS}, f_{\text{SCLK}} = 1.7 \text{ MHz}, V_{\text{DD}} = 1.2 \text{ V}$	0.24	0.3		
Power-down mode	SCLK on or off, $V_{\text{DD}} = 3.6 \text{ V}$				1.08	μW
TEMPERATURE RANGE						
Specified performance			-40	85		$^{\circ}\text{C}$

TIMING REQUIREMENTS⁽¹⁾⁽²⁾

At -40°C to 85°C , $f_{\text{SCLK}} = 3.4 \text{ MHz}$ if $1.6 \text{ V} \leq V_{\text{DD}} \leq 3.6 \text{ V}$; $f_{\text{SCLK}} = 1.7 \text{ MHz}$ if $1.2 \text{ V} \leq V_{\text{DD}} < 1.6 \text{ V}$, 50-pF Load on SDO Pin, unless otherwise noted

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{sample}	Sample time		$t_{\text{SU(CSF-FSCLKF)}} + 2 \times t_{\text{C(SCLK)}}$		μs
t_{convert}	Conversion time	ADS7866	13 $\times t_{\text{C(SCLK)}}$		μs
		ADS7867	11 $\times t_{\text{C(SCLK)}}$		
		ADS7868	9 $\times t_{\text{C(SCLK)}}$		
$t_{\text{C(SCLK)}}$	Cycle time	1.2 $\text{V} \leq V_{\text{DD}} < 1.6 \text{ V}$	See (3)	100	μs
		1.6 $\text{V} \leq V_{\text{DD}} < 1.8 \text{ V}$	See (3)	100	
		1.8 $\text{V} \leq V_{\text{DD}} < 2.5 \text{ V}$	See (3)	50	
		2.5 $\text{V} \leq V_{\text{DD}} \leq 3.6 \text{ V}$	See (3)	6.7	
$t_{\text{WH(SCLK)}}$	Pulse duration		$0.4 \times t_{\text{C(SCLK)}}$	$0.6 \times t_{\text{C(SCLK)}}$	ns
$t_{\text{WL(SCLK)}}$	Pulse duration		$0.4 \times t_{\text{C(SCLK)}}$	$0.6 \times t_{\text{C(SCLK)}}$	ns
$t_{\text{SU(CSF-FSCLKF)}}$	Setup time	1.2 $\text{V} \leq V_{\text{DD}} < 1.6 \text{ V}$	192		ns
		1.6 $\text{V} \leq V_{\text{DD}} < 1.8 \text{ V}$	55		
		1.8 $\text{V} \leq V_{\text{DD}} \leq 3.6 \text{ V}$	55		
$t_{\text{D(CSF-SDOVALID)}}$	Delay time	1.2 $\text{V} \leq V_{\text{DD}} < 1.6 \text{ V}$		65	ns
		1.6 $\text{V} \leq V_{\text{DD}} < 1.8 \text{ V}$		55	
		1.8 $\text{V} \leq V_{\text{DD}} \leq 3.6 \text{ V}$		55	
$t_{\text{H(SCLKF-SDOVALID)}}$	Hold time	1.2 $\text{V} \leq V_{\text{DD}} < 1.6 \text{ V}$	20		ns
		1.6 $\text{V} \leq V_{\text{DD}} < 1.8 \text{ V}$	10		
		1.8 $\text{V} \leq V_{\text{DD}} \leq 3.6 \text{ V}$	10		
$t_{\text{D(SCLKF-SDOVALID)}}$	Delay time	1.2 $\text{V} \leq V_{\text{DD}} < 1.6 \text{ V}$		140	ns
		1.6 $\text{V} \leq V_{\text{DD}} < 1.8 \text{ V}$		140	
		1.8 $\text{V} \leq V_{\text{DD}} \leq 3.6 \text{ V}$		140	
$t_{\text{DIS(EOC-SDOZ)}}$	Disable time	1.2 $\text{V} \leq V_{\text{DD}} < 1.6 \text{ V}$	10	80	ns
		1.6 $\text{V} \leq V_{\text{DD}} < 1.8 \text{ V}$	7	60	
		1.8 $\text{V} \leq V_{\text{DD}} \leq 3.6 \text{ V}$	7	60	
$t_{\text{WH(CS)}}$	Pulse duration	1.2 $\text{V} \leq V_{\text{DD}} < 1.6 \text{ V}$	20		ns
		1.6 $\text{V} \leq V_{\text{DD}} < 1.8 \text{ V}$	10		
		1.8 $\text{V} \leq V_{\text{DD}} \leq 3.6 \text{ V}$	10		
$t_{\text{SU(LSBZ-CSF)}}$	Setup time	1.2 $\text{V} \leq V_{\text{DD}} < 1.6 \text{ V}$	20		ns
		1.6 $\text{V} \leq V_{\text{DD}} < 1.8 \text{ V}$	10		
		1.8 $\text{V} \leq V_{\text{DD}} \leq 3.6 \text{ V}$	10		

(1) All input signals are specified with $t_r = t_f = 5 \text{ ns}$ (10% to 90% of V_{DD}) and timed from a voltage level of $(V_{\text{IL}} + V_{\text{IH}})/2$.

(2) See timing diagram in Figure 1.

(3) Min $t_{\text{C(SCLK)}}$ is determined by the Min t_{SAMPLE} of the specific resolution and supply voltage. See *Acquisition Time, Conversion Time, and Total Cycle Time* section for further details.

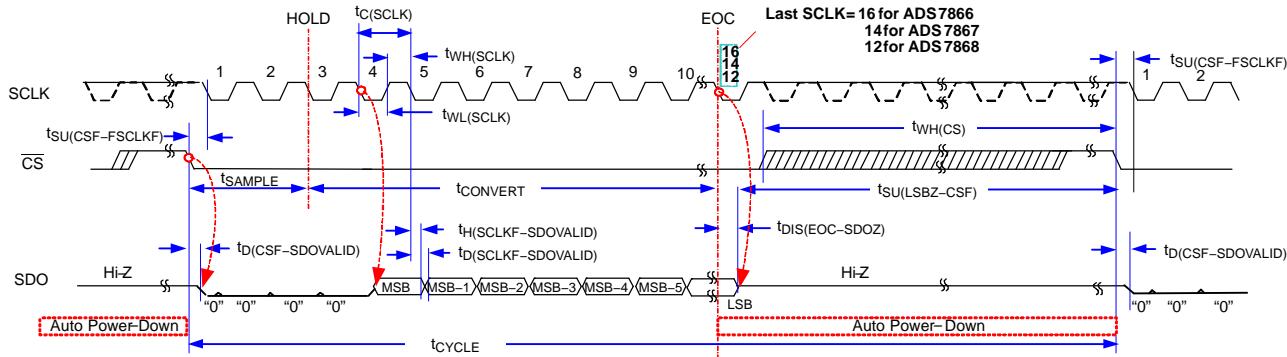
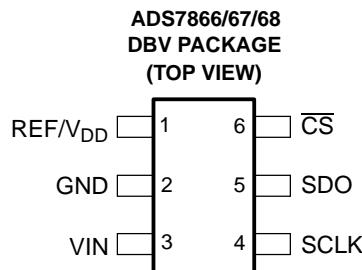


Figure 1. Timing Diagram

PIN CONFIGURATION



TERMINAL FUNCTIONS

TERMINAL	DESCRIPTION	
NAME	NO.	
REF/V _{DD}	1	External reference input and power supply
GND	2	Ground for signal and power supply. All analog and digital signals are referred with respect to this pin.
VIN	3	Analog signal input
SCLK	4	Serial clock input. This clock is used for clocking data out, and it is the source of conversion clock.
SDO	5	This is the serial data output of the conversion result. The serial stream comes with MSB first. The MSB is clocked out (changed) on the falling edge one SCLK after the sampling period ends. This results in four leading zeros after CS becomes active. SDO is 3-stated once all the valid bits are clocked out (12 for ADS7866, 10 for ADS7867, and 8 for ADS7868).
CS	6	This is an active low input signal. It is used as a chip select to gate the SCLK input, to initiate a conversion, and to frame output data.

TYPICAL CHARACTERISTICS ADS7866

FFT (8192 Points)

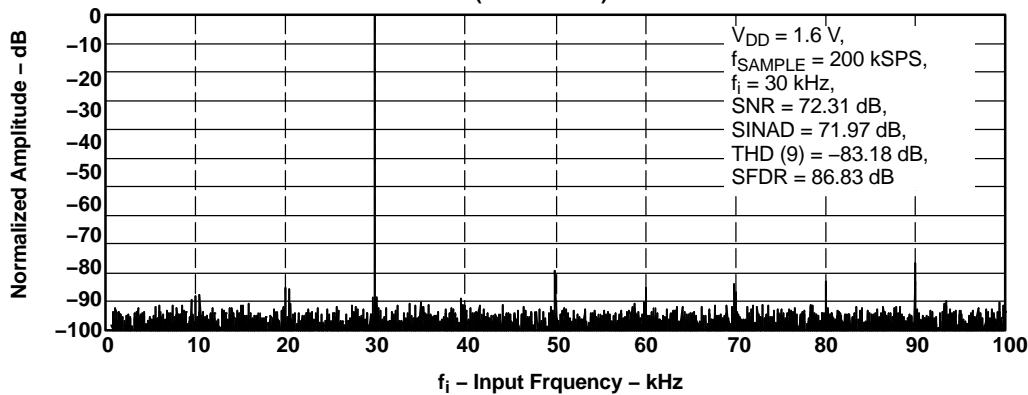


Figure 2.

FFT (8192 Points)

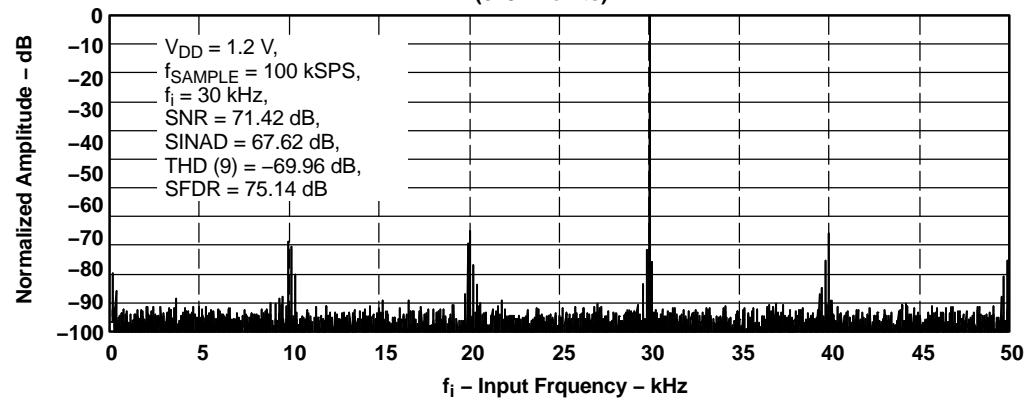


Figure 3.

SIGNAL-TO-NOISE RATIO
vs
INPUT FREQUENCY

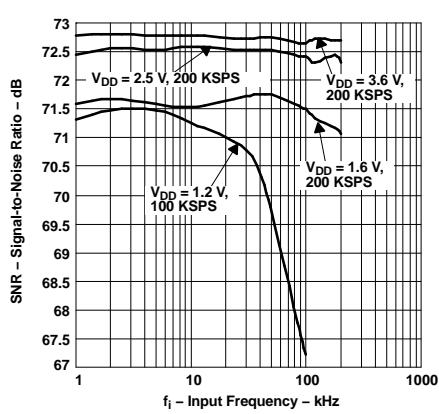


Figure 4.

SIGNAL-TO-NOISE
AND DISTORTION
vs
INPUT FREQUENCY

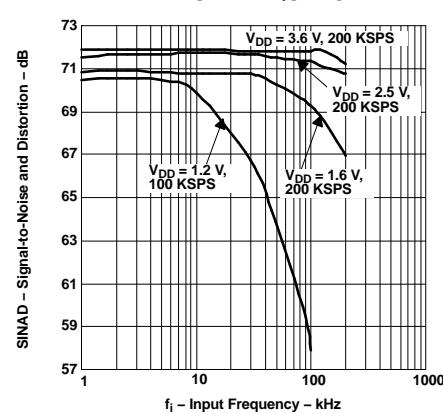


Figure 5.

TOTAL HARMONIC DISTORTION
vs
INPUT FREQUENCY

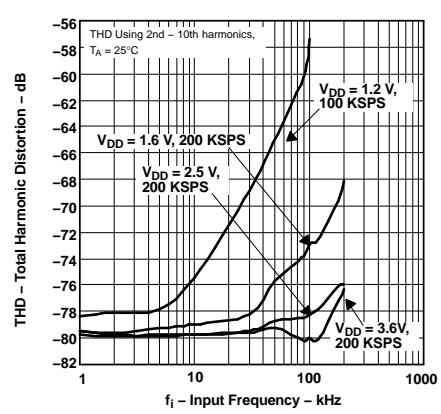


Figure 6.

TYPICAL CHARACTERISTICS ADS7866 (continued)

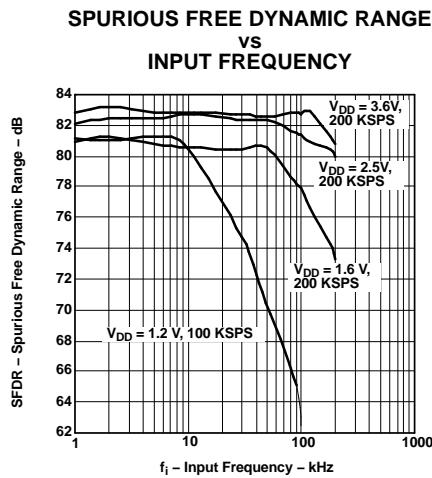


Figure 7.

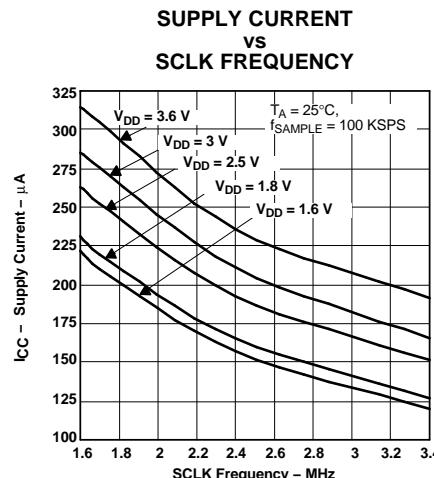


Figure 8.

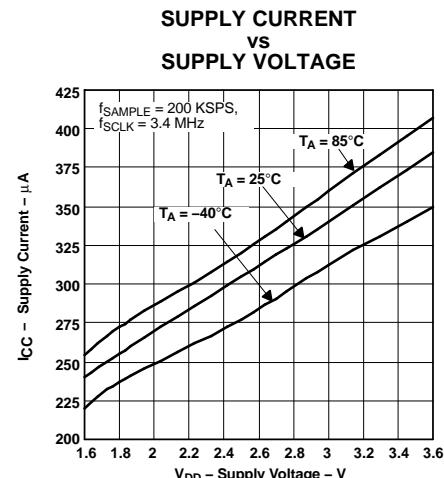


Figure 9.

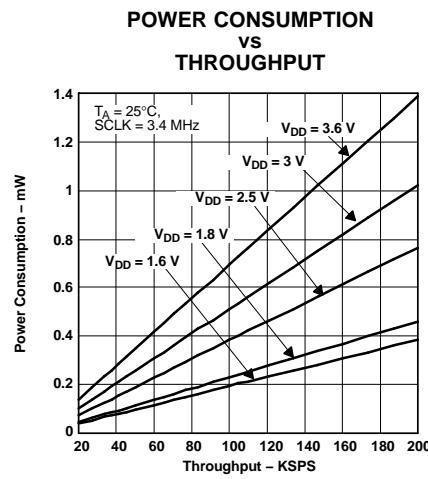


Figure 10.

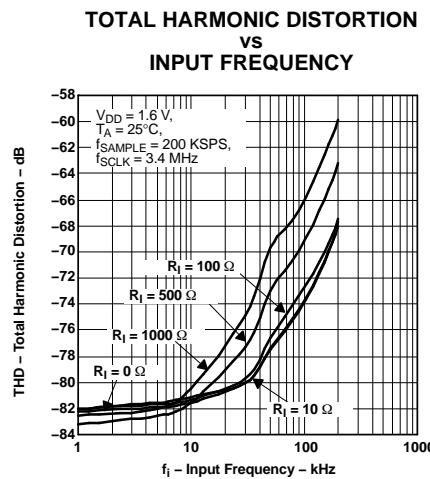
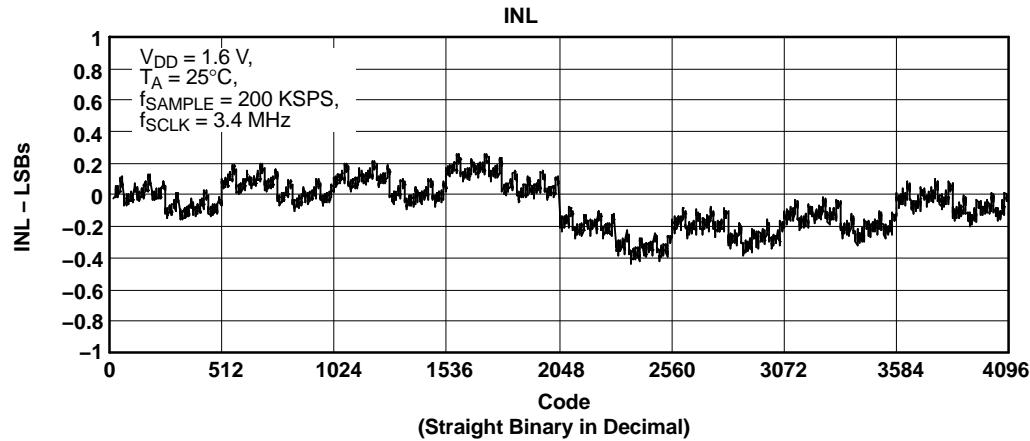


Figure 11.



(Straight Binary in Decimal)

Figure 12.

TYPICAL CHARACTERISTICS ADS7866 (continued)

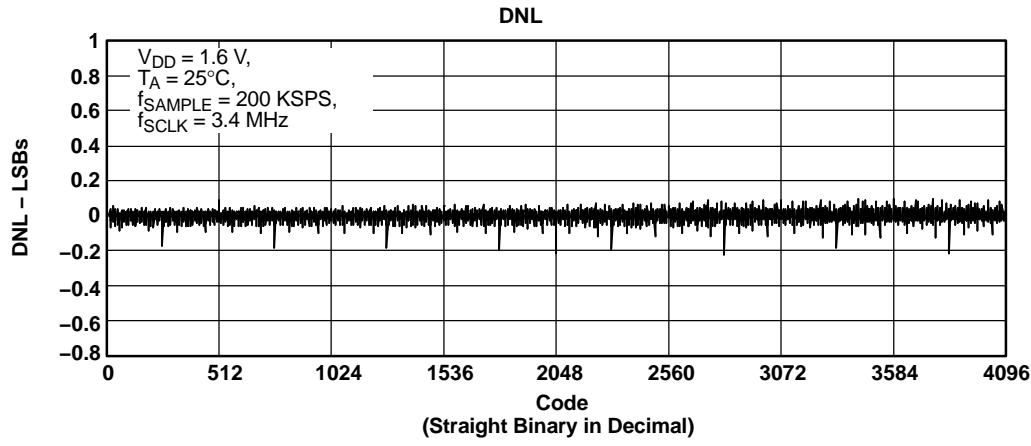


Figure 13.

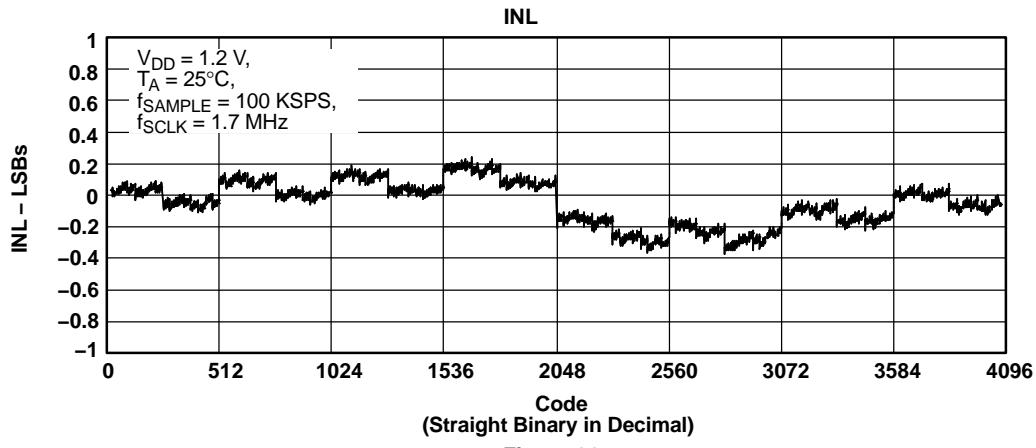


Figure 14.

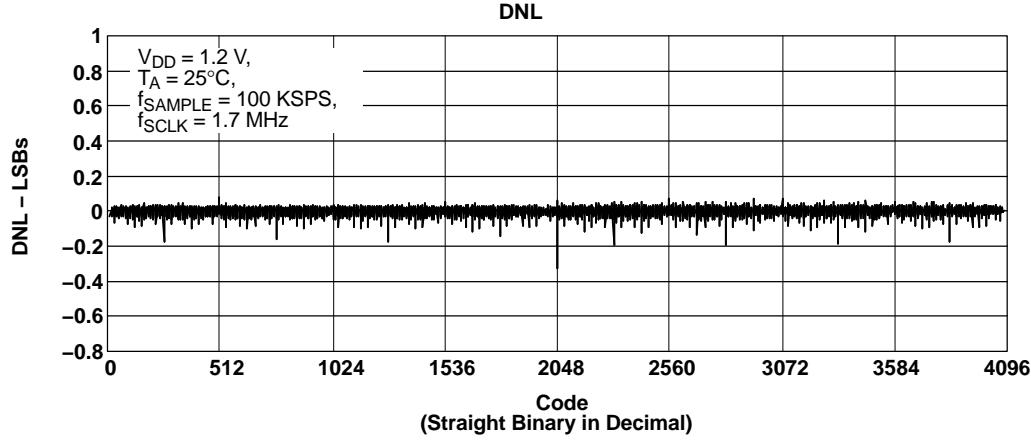


Figure 15.

TYPICAL CHARACTERISTICS ADS7866 (continued)

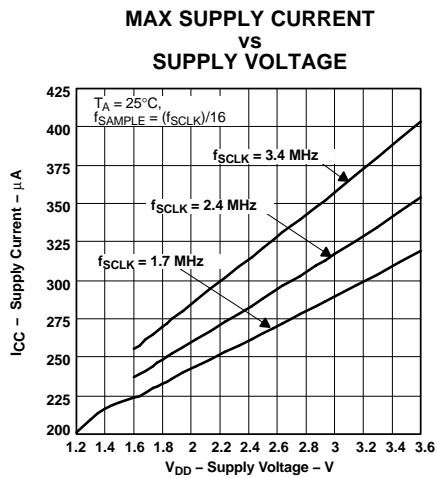


Figure 16.

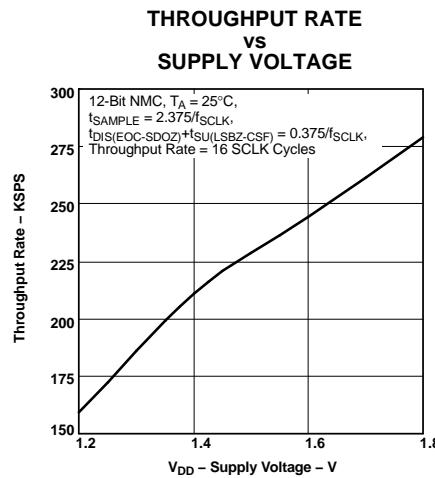


Figure 17.

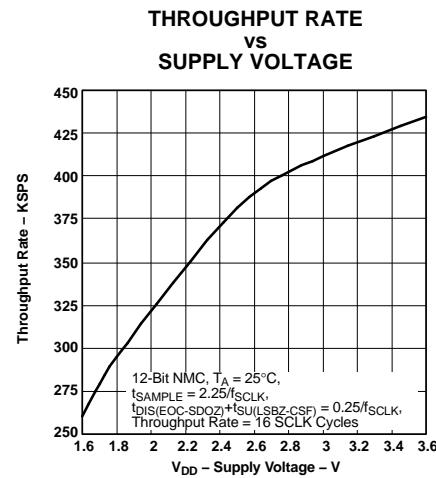


Figure 18.

TYPICAL CHARACTERISTICS ADS7867

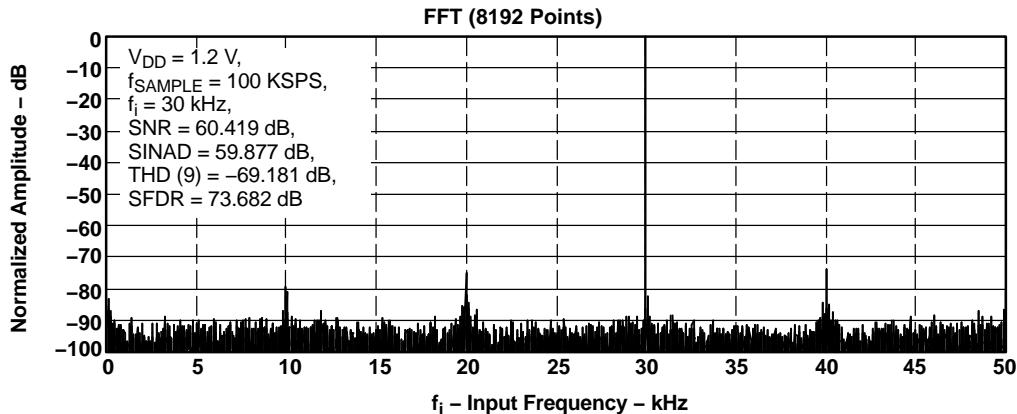


Figure 19.

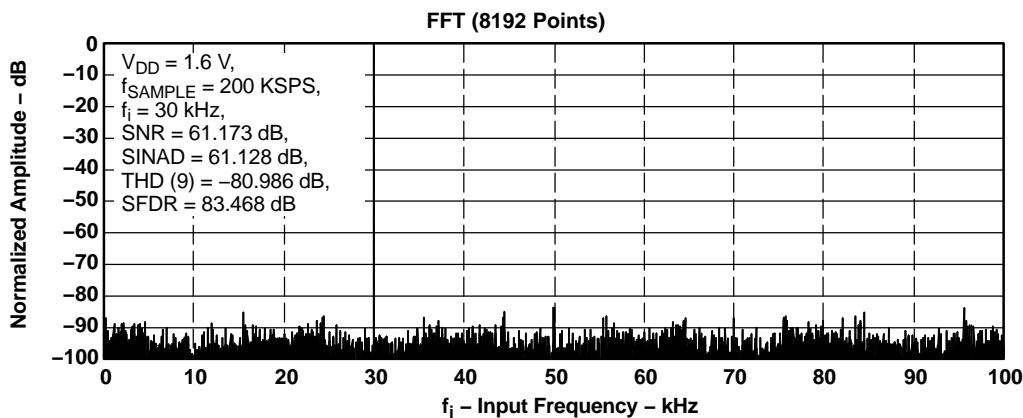


Figure 20.

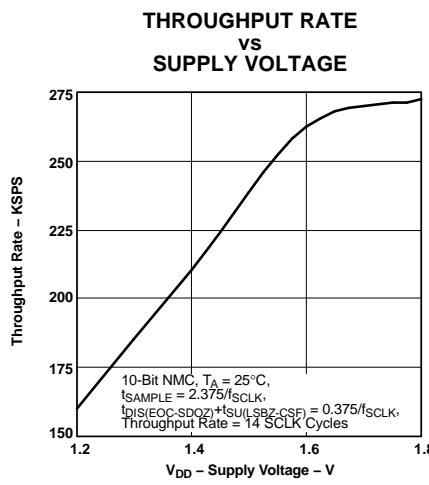


Figure 21.

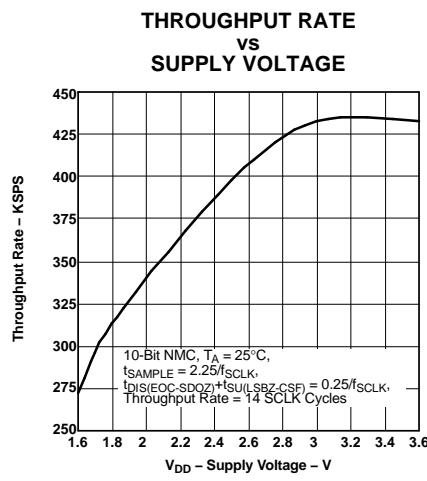


Figure 22.

TYPICAL CHARACTERISTICS ADS7868

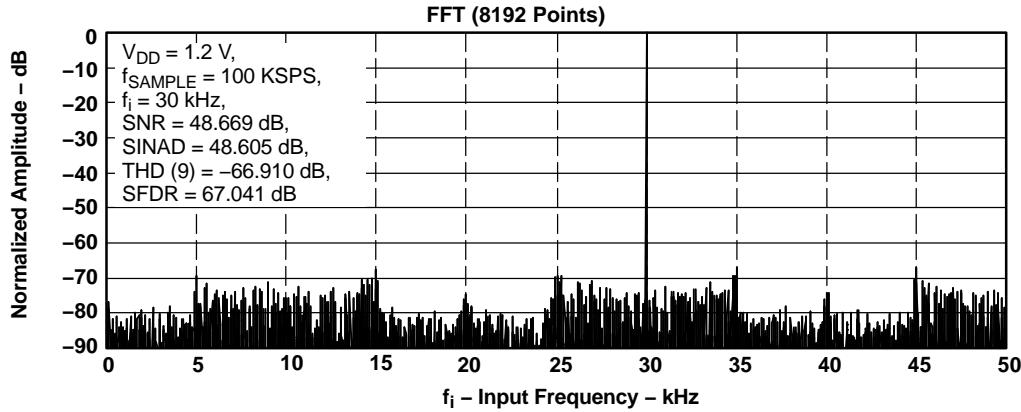


Figure 23.

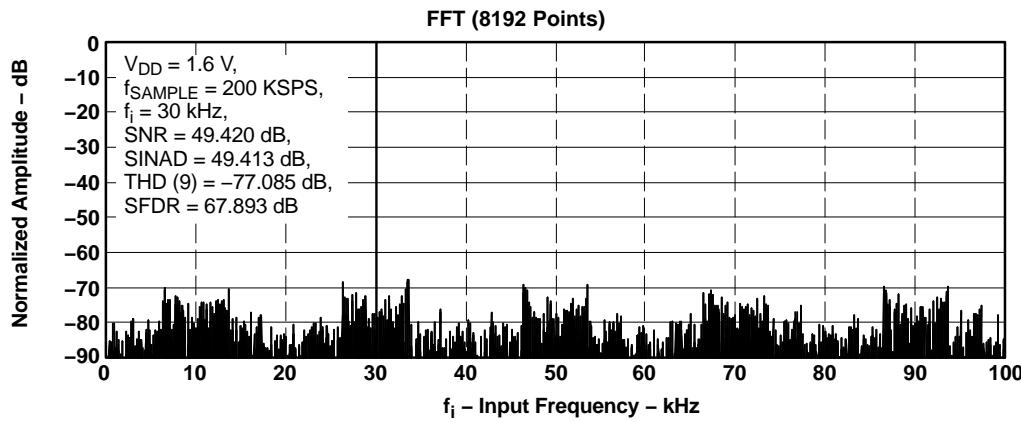


Figure 24.

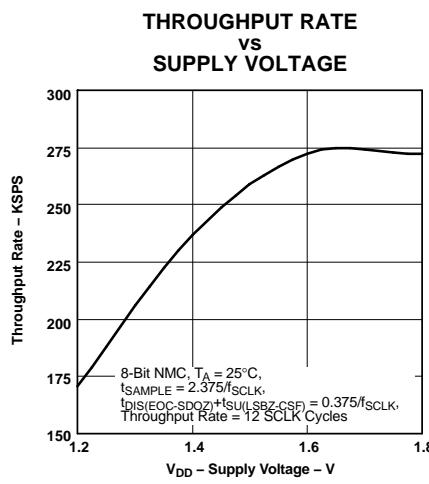


Figure 25.

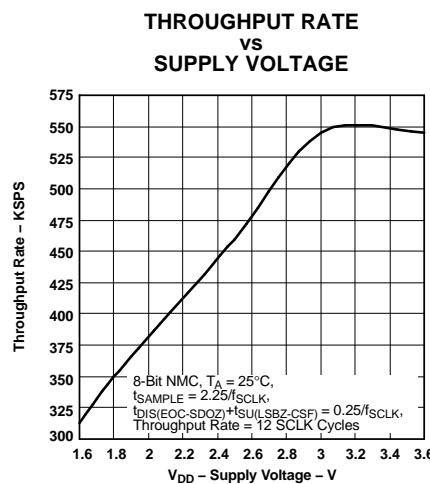


Figure 26.

THEORY OF OPERATION

The ADS7866/67/68 is a family of low supply voltage, low power, high-speed successive approximation register (SAR) analog-to-digital converters (ADCs). The devices can be operated from a supply range from 1.2 V to 3.6 V. There is no need for an external reference. The reference is derived internally from the supply voltage, so the analog input range can be from 0 V to V_{DD} . These ADCs use a charge redistribution architecture, which inherently includes a sample/hold function.

START OF A CONVERSION CYCLE

A conversion cycle is initiated by bringing the \overline{CS} pin low and supplying the serial clock SCLK. The time between the falling edge of \overline{CS} and the third falling edge of SCLK after \overline{CS} falls is used to acquire the input signal. This must be greater than or equal to the minimum acquisition time (MIN t_{SAMPLE} in [Table 1](#)) specified for the desired resolution and supply voltage. On the third falling edge of SCLK after \overline{CS} falls, the device goes into hold mode and the process of digitizing the sampled input signal starts.

Acquisition Time, Conversion Time, and Total Cycle Time

The maximum SCLK frequency is determined by the minimum acquisition time (MIN t_{SAMPLE}) specified for the specific resolution and supply voltage of the device. The conversion time is determined by the frequency of SCLK since this is a synchronous converter. The conversion time is 13 times the SCLK cycle time $t_{C(SCLK)}$ for the ADS7866, 11 times for the ADS7867, and 9 times for the ADS7868. The acquisition time, which is also the power up time, is the set-up time between the first falling edge of SCLK after \overline{CS} falls ($t_{SU(CSF-FSCLKF)}$) plus 2 times $t_{C(SCLK)}$.

The total cycle time, t_{CYCLE} , which is the inverse of the maximum sample rate, can be calculated as follows:

$$t_{CYCLE} = t_{SAMPLE} + t_{CONVERT} + 0.5 \times t_{C(SCLK)}$$

if $t_{DIS(EOC-SDOZ)} + t_{SU(LSBZ-CSF)} \leq 0.5 \times t_{C(SCLK)}$

$$t_{CYCLE} = t_{SAMPLE} + t_{CONVERT} + t_{DIS(EOC-SDOZ)} + t_{SU(LSBZ-CSF)}$$

if $t_{DIS(EOC-SDOZ)} + t_{SU(LSBZ-CSF)} > 0.5 \times t_{C(SCLK)}$

THEORY OF OPERATION (continued)

Table 1. Acquisition, Conversion, SCLK, and Potential Throughput Calculation

PARAMETER	SUPPLY VOLTAGE	ADS7866	ADS7867	ADS7868	UNIT
MIN $t_{SU(CSF-FSCLKF)}$	1.2 V $\leq V_{DD} < 1.6$ V	192	192	192	ns
	1.6 V $\leq V_{DD} < 1.8$ V	55	55	55	
	1.8 V $\leq V_{DD} \leq 3.6$ V	55	55	55	
MAX $t_{DIS(EOC-SDOZ)}$	1.2 V $\leq V_{DD} < 1.6$ V	80	80	80	ns
	1.6 V $\leq V_{DD} < 1.8$ V	60	60	60	
	1.8 V $\leq V_{DD} \leq 3.6$ V	60	60	60	
MIN $t_{SU(LSBZ-CSF)}$	1.2 V $\leq V_{DD} < 1.6$ V	20	20	20	ns
	1.6 V $\leq V_{DD} < 1.8$ V	10	10	10	
	1.8 V $\leq V_{DD} \leq 3.6$ V	10	10	10	
MAX f_{SCLK}	1.2 V $\leq V_{DD} < 1.6$ V	1.7	1.7	1.7	MHz
	1.6 V $\leq V_{DD} < 1.8$ V	3.4	3.4	3.4	
	1.8 V $\leq V_{DD} \leq 3.6$ V	3.4	3.4	3.4	
MIN t_{sample}	1.2 V $\leq V_{DD} < 1.6$ V	1368	1368	1368	ns
	1.6 V $\leq V_{DD} < 1.8$ V	643	643	643	
	1.8 V $\leq V_{DD} \leq 3.6$ V	643	643	643	
MIN $t_{convert}$	1.2 V $\leq V_{DD} < 1.6$ V	7647	6471	5294	ns
	1.6 V $\leq V_{DD} < 1.8$ V	3824	3235	2647	
	1.8 V $\leq V_{DD} \leq 3.6$ V	3824	3235	2647	
MIN t_{CYCLE}	1.2 V $\leq V_{DD} < 1.6$ V	9116	7939	6763	ns
	1.6 V $\leq V_{DD} < 1.8$ V	4537	3949	3360	
	1.8 V $\leq V_{DD} \leq 3.6$ V	4537	3949	3360	
f_{sample}	1.2 V $\leq V_{DD} < 1.6$ V	110	126	148	KSPS
	1.6 V $\leq V_{DD} < 1.8$ V	220	253	298	
	1.8 V $\leq V_{DD} \leq 3.6$ V	220	253	298	

TYPICAL CONNECTION

For a typical connection circuit for the ADS7866/67/68 see [Figure 27](#). A REF3112 is used to supply 1.2 V to the device. A 0.1- μ F decoupling capacitor is required between the REF/ V_{DD} and GND pins of the converter. This capacitor should be placed as close as possible to the pins of the device. Designers should strive to minimize the routing length of the traces that connect the terminals of the capacitor to the pins of the converter.

Keep in mind the converter offers no inherent rejection of noise or voltage variation in regards to the reference input. This is of particular concern because the reference input is tied to the power supply. Any noise and ripple from the supply appears directly in the digital results. While high frequency noise can be filtered out as described in the previous paragraph, voltage variation due to the line frequency (50 Hz or 60 Hz) can be difficult to remove.

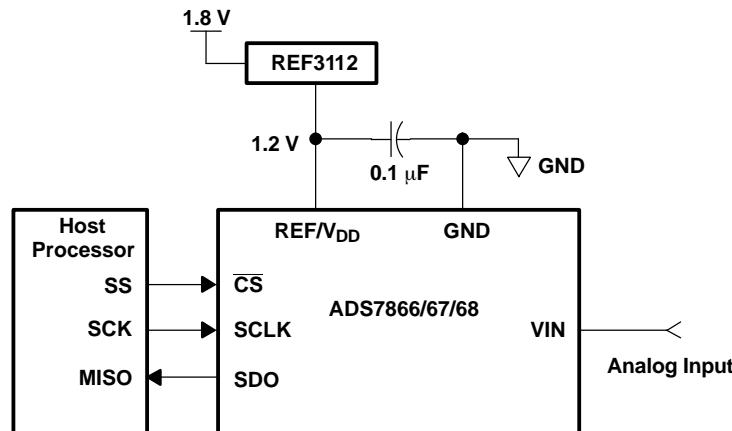


Figure 27. Typical Circuit Configuration

ANALOG INPUT

Figure 28 shows the analog input equivalent circuit for the ADS7866/67/68. The analog input is provided between the VIN and GND pins. When a conversion is initiated, the input signal is sampled on the internal capacitor array. When the converter enters hold mode, the input signal is captured on the internal capacitor array. The VIN input range is limited to 0 V to V_{DD} because the reference is derived from the supply.

The current flowing into the analog input depends upon a number of factors, such as the sample rate, the input voltage, and the input source impedance. The current from the input source charges the internal capacitor array during the sample period. After this capacitance has been fully charged, there is no further input current. The source of the analog input voltage must be able to charge the input capacitance C_S (12 pF typical) within the minimum acquisition time (MIN t_{SAMPLE}) specified for the desired resolution and supply voltage. In the case of the ADS7866, the MIN t_{SAMPLE} for 12-bit resolution is 643 ns (V_{DD} between 1.6 V and 3.6 V). When the converter goes into hold mode, the input impedance is greater than 1 G Ω .

Care must be taken regarding the absolute analog input voltage. In order to maintain the linearity of the converter, the span (VIN – GND) should be within the limits specified. Outside of these limits, the converter's linearity may not meet specifications. Noise introduced into the converter from the input source may be minimized by using low bandwidth input signals along with low-pass filters.

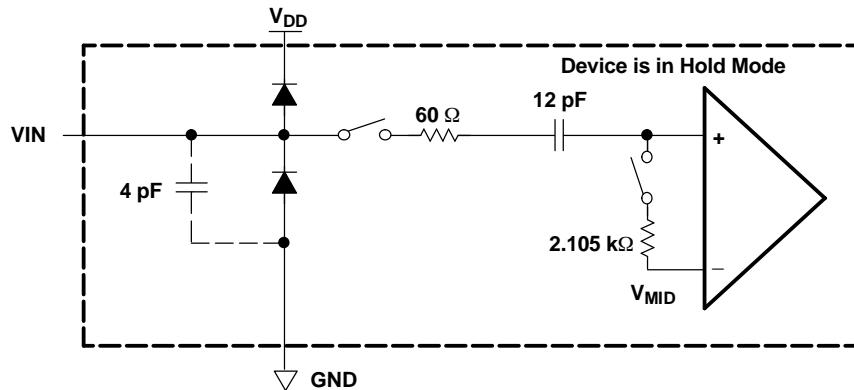


Figure 28. Analog Input Equivalent Circuit (Typical Impedance Values at $V_{DD} = 1.6$ V, $T_A = 27^\circ\text{C}$)

Choice of Input Driving Amplifier

The analog input to the converter needs to be driven with a low noise, low voltage op amp like the OPA364 or OPA333. An RC filter is recommended at the input pin to low-pass filter the noise from the source. The input to the converter is a unipolar input voltage in the range 0 V to V_{DD} .

DIGITAL INTERFACE

The ADS7866/67/68 interface with microprocessors or DSPs through a high-speed SPI compatible serial interface with CPOL = 1 (inactive SCLK returns to logic high or SCLK leading edge is the rising edge), CPHA = 1 (output data changes on falling edge of SCLK and is available on the rising edge of SCLK). The sampling, conversion, and activation of SDO are initiated on the falling edge of $\overline{\text{CS}}$. The serial clock (SCLK) is used for controlling the rate of conversion. It also provides a mechanism allowing synchronization with digital host processors.

The digital inputs, $\overline{\text{CS}}$ and SCLK, can exceed the supply voltage V_{DD} as long as they do not exceed the maximum V_{IH} of 3.6 V. This allows the ADS7866/67/68 family to interface with host processors which use a different supply voltage than the converter without requiring external level-shifting circuitry. Furthermore, the digital inputs can be applied to $\overline{\text{CS}}$ and SCLK before the supply voltage of the converter is activated without the risk of creating a latch-up condition.

Conversion Result

The ADS7866/67/68 outputs 12/10/8-bit data after 4 leading zeros, respectively. These codes are in straight binary format as shown in Table 2.

The serial output SDO is activated on the falling edge of \overline{CS} . The first leading zero is available on SDO until the first falling edge of SCLK after \overline{CS} falls. The remaining 3 leading zeros are shifted out on SDO on the first, second, and third falling edges of SCLK after \overline{CS} falls. The MSB of the converted result follows 4 leading zeros and is clocked out on the fourth falling edge of SCLK. The rising edge of \overline{CS} or the falling edge of SCLK when the EOC occurs puts SDO output into 3-state. Refer to [Table 2](#) for ideal output codes versus input voltages.

Table 2. ADS7866/67/68 Ideal Output Codes Versus Input Voltages

DESCRIPTION	ANALOG INPUT VOLTAGE	DIGITAL OUTPUT STRAIGHT BINARY	
		BINARY CODE	HEX CODE
ADS7866			
Least Significant Bit (LSB)	$V_{DD}/4096$		
Full Scale	$V_{DD} - 1\text{ LSB}$	1111 1111 1111	FFF
Midscale	$V_{DD}/2$	1000 0000 0000	800
Midscale – 1LSB	$V_{DD}/2 - 1\text{ LSB}$	0111 1111 1111	7FF
Zero	0V	0000 0000 0000	000
ADS7867			
Least Significant Bit (LSB)	$V_{DD}/1024$		
Full Scale	$V_{DD} - 1\text{ LSB}$	11 1111 1111	3FF
Midscale	$V_{DD}/2$	10 0000 0000	200
Midscale – 1LSB	$V_{DD}/2 - 1\text{ LSB}$	01 1111 1111	1FF
Zero	0V	00 0000 0000	000
ADS7868			
Least Significant Bit (LSB)	$V_{DD}/256$		
Full Scale	$V_{DD} - 1\text{ LSB}$	1111 1111	FF
Midscale	$V_{DD}/2$	1000 0000	80
Midscale – 1LSB	$V_{DD}/2 - 1\text{ LSB}$	0111 1111	7F
Zero	0V	0000 0000	00

POWER DISSIPATION

The ADS7866/67/68 family is capable of operating with very low supply voltages while drawing a fraction of a milliamp. Furthermore, there is an auto power-down mode to reduce the power dissipation between conversion cycles. Carefully selected system design can take advantage of these features to achieve optimum power performance.

Auto Power-Down Mode

The ADS7866/67/68 family has an auto power-down feature. Besides powering down all circuitry, the converter consumes only 8 nA typically in this mode. The device automatically wakes up when \overline{CS} falls. However, not all of the functional blocks are fully powered until sometime before the third falling edge of SCLK. The device powers down once it reaches the end of conversion (EOC) which is the 16th falling edge of SCLK for the ADS7866 (the 14th and 12th for the ADS7867 and ADS7868, respectively). If \overline{CS} is pulled high before the device reaches the EOC, the converter goes into power-down mode and the ongoing conversion is aborted. Refer to the timing diagram in [Figure 1](#) for further information.

Power Saving: SCLK Frequency and Throughput

These converters achieve lower power dissipation for a fixed throughput rate $f_{\text{sample}} = 1/t_{\text{cycle}}$ by using higher SCLK frequencies. Higher SCLK frequencies reduce the acquisition time (t_{sample}) and conversion time (t_{convert}). This means the converters spend more time in auto power-down mode per conversion cycle. This can be observed in [Figure 8](#) which shows the ADS7866 supply current versus SCLK frequency for $f_{\text{sample}} = 100$ KSPS. For a particular SCLK frequency, the acquisition time and conversion time are fixed. Therefore, a lower throughput increases the proportion of the time the converters are in power down. [Figure 10](#) shows this case for the ADS7866 power consumption versus throughput rate for $f_{\text{SCLK}} = 3.4$ MHz.

Power-On Initialization

There is no specific initialization requirement for these converters after power-on, but the first conversion might not yield a valid result. In order to set the converter in a known state, \overline{CS} should be toggled low then high after V_{DD} has stabilized during power-on. By doing this, the converter is placed in auto power-down mode, and the serial data output (SDO) is 3-stated.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
ADS7866IDBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A66Y	Samples
ADS7866IDBVRG4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A66Y	Samples
ADS7866IDBVT	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A66Y	Samples
ADS7866IDBVTG4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A66Y	Samples
ADS7867IDBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A67Y	Samples
ADS7867IDBVT	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-250C-1 YEAR	-40 to 85	A67Y	Samples
ADS7867IDBVTG4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-250C-1 YEAR	-40 to 85	A67Y	Samples
ADS7868IDBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A68Y	Samples
ADS7868IDBVRG4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A68Y	Samples
ADS7868IDBVT	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A68Y	Samples
ADS7868IDBVTG4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A68Y	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

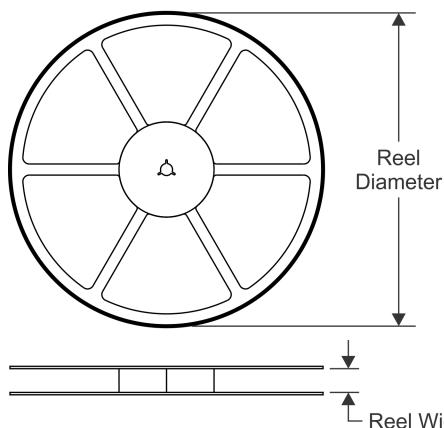
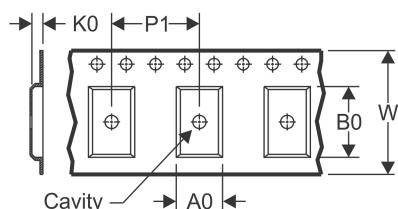
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

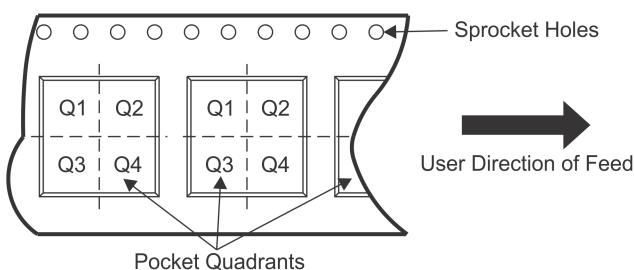
(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION
REEL DIMENSIONS

TAPE DIMENSIONS


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ADS7866IDBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.1	1.39	4.0	8.0	Q3
ADS7866IDBVT	SOT-23	DBV	6	250	180.0	8.4	3.2	3.1	1.39	4.0	8.0	Q3
ADS7867IDBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.1	1.39	4.0	8.0	Q3
ADS7867IDBVT	SOT-23	DBV	6	250	180.0	8.4	3.2	3.1	1.39	4.0	8.0	Q3
ADS7868IDBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.1	1.39	4.0	8.0	Q3
ADS7868IDBVT	SOT-23	DBV	6	250	180.0	8.4	3.2	3.1	1.39	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS

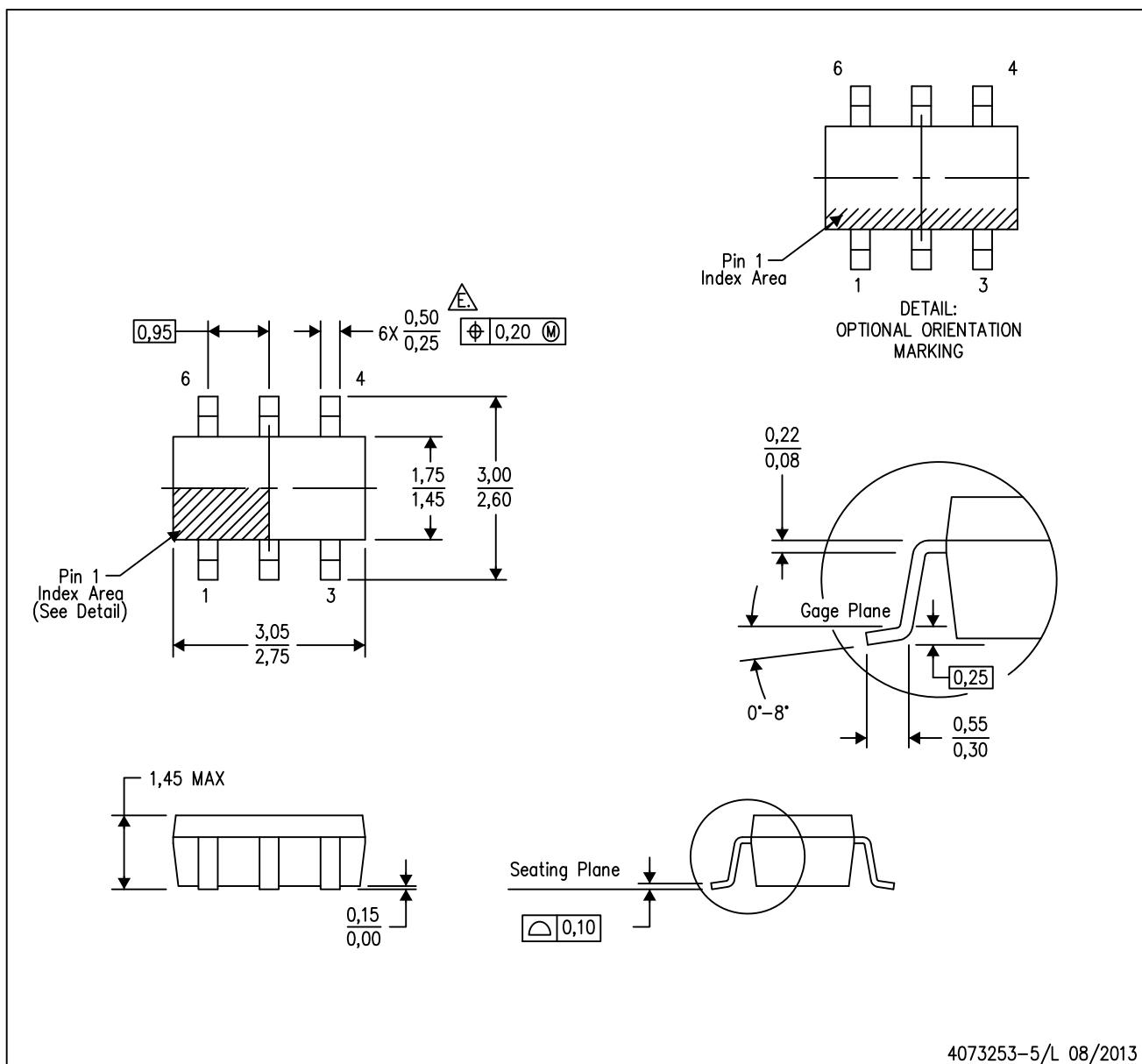

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ADS7866IDBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0
ADS7866IDBVT	SOT-23	DBV	6	250	210.0	185.0	35.0
ADS7867IDBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0
ADS7867IDBVT	SOT-23	DBV	6	250	210.0	185.0	35.0
ADS7868IDBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0
ADS7868IDBVT	SOT-23	DBV	6	250	210.0	185.0	35.0

MECHANICAL DATA

DBV (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



4073253-5/L 08/2013

NOTES:

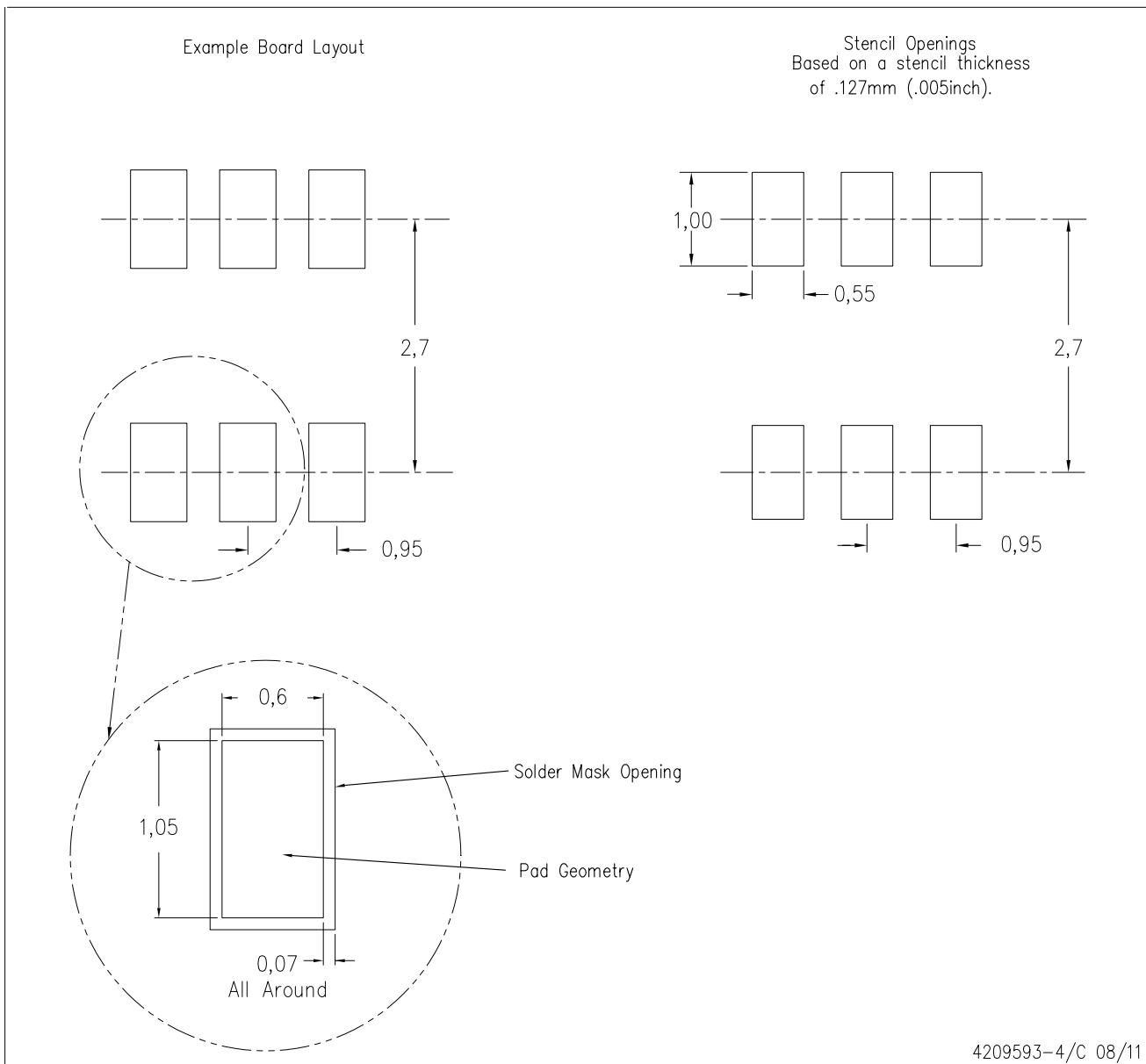
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.

△ Falls within JEDEC MO-178 Variation AB, except minimum lead width.

LAND PATTERN DATA

DBV (R-PDSO-G6)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

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